Valence-Ordered Thin-Film Nickelate with Tricomponent Nickel Coordination Prepared by Topochemical Reduction

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ABSTRACT: The metal-hydride-based "topochemical reduc-tion" process has produced several thermodynamically unstable phases across various transition metal oxide series with unusual crystal structures and nontrivial ground states. Here, by such an oxygen (de-)intercalation method we synthesis a samarium nickelate with ordered nickel valences associated with tri-component coordination configurations. This structure, with a formula of $Sm_9Ni_9O_{22}$ as revealed by four-dimensional scanning transmission electron microscopy (4D-STEM), emerges from the intricate planes of $\{303\}_{pc}$ ordered apical oxygen vacancies. X-ray spectroscopy measurements and ab initio calculations show the coexistence of square planar, pyramidal, and octahedral Ni sites with mono-, bi-, and tri-valences. It leads to an intense orbital polarization, charge-ordering, and a ground state with a strong electron localization marked by the disappearance of ligand-hole configuration at low temperature. This nickelate compound provides another example of previously inaccessible materials enabled by topotactic transformations and presents an interesting platform where mixed Ni valence can give rise to exotic phenomena.

The on-demand design of transition-metal oxides (TMOs) with emerging properties is imparted by the multivalent nature of the transition-metal ions and the accessible complexity of lattice structures.^{1,2} Varying the structure and constituent elements in TMO allows access to a range of competing ground states and exotic electronic landscapes, in which the interplay of the transition-metal orbitals and the connecting oxygen network often plays an essential role.³ One phenomenal example is the cuprate family, where different c oordinational C u-O f rameworks l ead to distinctive T_c (T_{ct} superconducting transition temperature) values.⁴ In addition, the fast developments in topotactic softchemistry approaches have enabled the synthesis of unconventional TMO with unusual valence states and/or oxygen connectivity.⁵⁻⁷ One of the recent seminal examples is the synthesis of a family of superconducting low-valence nickelates $^{8-1}$ by a topotactic reduction process, which displays intriguing analogies and distinctions to the high- T_c cuprates and is the focus of the current extensive research.

Nickel oxides or nickelates form a large family of structures with diverse crystalline configurations and e lectronic properties. Perovskite rare-earth nickelates $RNiO_3$ have a rich phase diagram generated by changing the rare-earth cation. They exhibit metal-to-insulator, magnetic, and structural transitions, $^{12-14}$ and upon stoichiometry alteration such as oxygen deintercalation or protonization can become reconfigurable neuromorphic devices.¹⁵ Upon a strong topotactic oxygen reduction, $RNiO_2$ infinite-layer n ickelates c an b e obtained, which have recently been discovered as superconducting after hole-doping.⁸ While the origin of most of these properties is not yet fully understood, the interplay of spin, charge, and

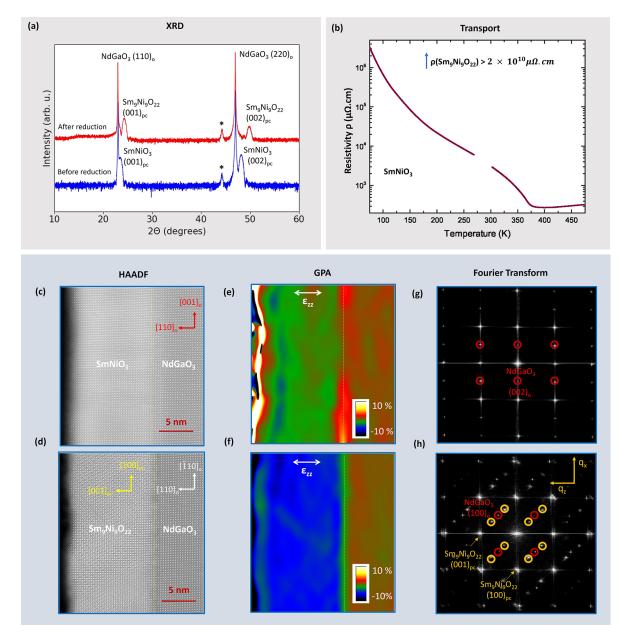


Figure 1. Structural and transport comparison of SmNiO₃ with Sm₉Ni₉O₂₂ by XRD, HAADF-STEM imaging, GPA, and FT. (a) XRD comparison of both. The 001 and 002 peaks for SmNiO₃ occur at lower 2 θ values compared to the 001 and 002 peaks of Sm₉Ni₉O₂₂, indicating an out-of-plane (o-o-p) compression of the pseudocubic (pc) unit cell upon reduction. Note that the artifact peaks labeled by asterisk are from the diffractometer. (b) Transport measurement of parent SmNiO₃ in increasing and decreasing temperatures. The resistivity curve of Sm₉Ni₉O₂₂ is not included in the plot since it was significantly higher and is beyond the detection range of the equipment (>2 × 10¹⁰ $\mu\Omega$ ·cm). (c) HAADF-STEM image of SmNiO₃ thin film. (d) HAADF-STEM image of Sm₉Ni₉O₂₂ thin film, showing in good contrast the stripes coinciding with the (303)_{pc} direction. (e and f) Maps of the o-o-p strain by GPA in (e) SmNiO₃ and (f) Sm₉Ni₉O₂₂. Both samples show uniform o-o-p compression. Sm₉Ni₉O₂₂ exhibits a more negative ϵ_{zz} compared to SmNiO₃, corresponding to a lower o-o-p parameter. (g and h) Corresponding FT of the HAADF image of (g) SmNiO₃ and (h) Sm₉Ni₉O₂₂. The NGO substrate is indexed with an orthorhombic unit cell, and the superstructure spots associated with the tilt pattern of the NGO are encircled in red. The superstructure spots associated with the (303)_{pc} stripes in Sm₉Ni₉O₂₂ are encircled in yellow and are indexed within a pseudocubic unit cell.

orbital degrees of freedom is known to drive these exotic properties, along with the associated crystalline configurations.

In the case of infinite-layer nickelate superconductors, a structurally perfect infinite-layer thin film is essential to achieve superconductivity.¹⁶ The topotactic reduction method for infinite-layer nickelate synthesis involves metal hydride, e.g., CaH₂, to remove the apical oxygens from a perovskite nickelate. This often results in a mixture of secondary phases with partial removal of apical oxygen.^{17,18} This is due to the

partial instability attributed to the infinite-layer structure that does not host Ni²⁺ (3d⁸) but a Ni¹⁺ in a 3d⁹ configuration.¹⁹ Along with superconductivity, the observed charge ordering $(CO)^{20-23}$ in these systems now appears to be connected to a structural reordering due to oxygen intercalation in the apical sites.^{24,25} Nevertheless, the structure of the charge-ordered systems cannot be directly related to known phases, such as brownmillerite¹⁷ or octahedra and square planar bearing R₃Ni₃O₇ phase where Ni²⁺ is absent.²⁶ The complex transport

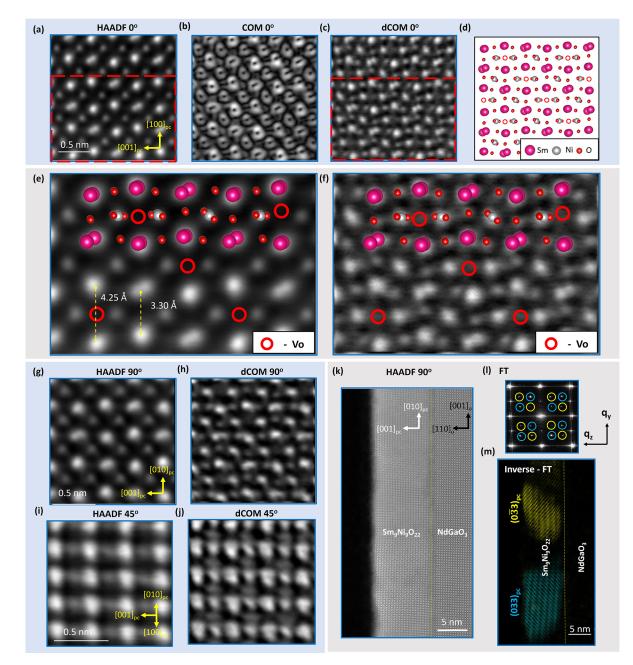


Figure 2. 4D-STEM analysis of Sm₉Ni₉O₂₂ in 0, 90, and 45° orientations that correspond to [010], [100], and [110]_{pc} viewing axes. (a) HAADF image of Sm₉Ni₉O₂₂ viewed along [010], showing doubled rare-earth sites and elongated-shortened Sm-Sm distances. (b) Absolute intensity COM image of the same region, obtained by 4D-STEM analysis. (c) Corresponding dCOM image, with a very good oxygen phase contrast, that shows the Vo line between the extended Sm-Sm distance, hence along the stripes. (d) Relaxed structural model that is identical to the dCOM image in panel c. (e) Magnified HAADF image of region highlighted in panel a, indicating the location of each atom and showing the extended and reduced regions with and without Vo. (f) Magnified dCOM image of region highlighted in panel c, indicating the location of each atom, and periodic Vo. (g) HAADF image of Sm₉Ni₉O₂₂ viewed along [100], showing features similar to those in the view along [010]. (h) Corresponding dCOM image. (i) HAADF image of Sm₉Ni₉O₂₂ viewed along [110], (j) Corresponding dCOM image. (k) Low-magnification HAADF image of Sm₉Ni₉O₂₂ viewed along [100], that shows stripes along (033)_{pc} and (033)_{pc} directions. (l) Corresponding FT showing spots at Q = $(0, \pm \frac{1}{3}, \pm \frac{1}{3}), (0, \pm \frac{2}{3}, \pm \frac{2}{3}), (0, \pm \frac{2}{3}, \mp \frac{1}{3}), (0, \pm \frac{2}{3}, \mp \frac{2}{3})$ rul. (m) Inverse-FT image showing the two domains obtained from the highlighted spots in panel 1.

properties and notably the unusual dramatic resistivity increase upon oxygen deintercalation of the perovskite nickelates $RNiO_3$ is also intriguing.²⁷

This concomitance indicates the possible existence of an unknown stable intermediate phase with multivalent, strong

electron localization and charge ordered ground state between the perovskite ABO₃ and the infinite-layer ABO₂.

Here, we demonstrate that the topochemical reduction of a perovskite $SmNiO_3$ thin film grown on an orthorhombic $NdGaO_3$ substrate stabilizes to such an intermediate phase

whose stoichiometry is derived as $\rm Sm_9Ni_9O_{22}$. This ubiquitous phase existing between the much pronounced perovskite $\rm ABO_3$ and the infinite-layer $\rm ABO_2$ nickelates hosts intriguing properties associated with multivalent and multicomponent coordinated Ni sites. Intriguing properties of this phase include a strong-orbital polarization, temperature dependent carrier localization, and charge ordering. The observed structural and electronic properties from microscopy and spectroscopy are validated by ab initio simulations, contributing to a coherent analysis and uncovering some regions of its possibly rich phase diagram.

RESULTS AND DISCUSSIONS

Origin of Phases from the {303}_{pc} Apical Oxygen Vacancy ordering. We begin with a macroscopic comparison between the parent perovskite SmNiO₃ and the reduced Sm₉Ni₉O₂₂ thin films, using X-ray diffraction (XRD) and transport measurements. As shown in Figure 1a, we find that the reduction of SmNiO₃ results in a scaling down of the pseudocubic (pc) out-of-plane (0-0-p) lattice parameter from 3.78 to 3.63 Å, indicative of a structural transition to the reduced Sm₉Ni₉O₂₂ phase. The quality of the thin film is confirmed by the intense Bragg peaks in the XRD scans and the finite-size oscillations in the X-ray reflectivity scans (not shown here). Additionally, in the transport measurements shown in Figure 1b, SmNiO₃ evidence a semiconducting behavior with an increase in conductivity of 4 orders of magnitude between 75 K and room-temperature, and a metalto-insulator transition around 375 K. This is in agreement with previous reports on SmNiO₃ thin films.²⁸ On the other hand, the resistivity of Sm₉Ni₉O₂₂ was above the measurement range > 2 × 10¹⁰ $\mu\Omega$ ·cm making it highly insulating with respect to its parent phase.

The microscopic characterization begins with a structural comparison between the parent perovskite SmNiO₃ and the reduced Sm₉Ni₉O₂₂ thin films, using high-angle annular darkfield (HAADF)-STEM imaging, geometrical phase analysis (GPA),²⁹ and Fourier transform (FT) analysis. As shown in Figure 1c,d, the HAADF-STEM image shows homogeneous thin films for both SmNiO₃ and Sm₉Ni₉O₂₂, with a coherent growth obtained on the $(110)_0$ cut NdGaO₃ substrate (where subscript "o" stands for the orthorhombic unit cell in the Pbnm space group with *a* = 5.433 Å, *b* = 5.504 Å, and *c* = 7.716 Å. In pseudocubic notation, this would be $a_{pc} = b_{pc} = 3.86$ Å and c_{pc} = 3.858 Å.). Panels e and f of Figure 1 show the maps of o-o-p strain from GPA analysis. The SmNiO₃ films have a uniform oo-p reduction of 3% as compared to the substrate, corresponding to a pseudocubic o-o-p parameter of 3.78 Å (for additional structural details, see Supporting Information, Section 1). On the other hand, the Sm₉Ni₉O₂₂ films have a uniform pseudocubic o-o-p parameter of 3.63 Å. Such uniformity indicates a high crystalline quality devoid of any defects, which is also visible at a larger field of view (see Supporting Information, Figure S1). Furthermore, Sm₉Ni₉O₂₂ have faint but robust contrasts corresponding to $(303)_{pc}$ oriented stripes which result in superstructure spots in the Fourier transform (FT) shown in Figure 1h at $Q = (\pm \frac{1}{3}, 0, \pm \frac{1}{3})$), $(\pm \frac{2}{3}, 0, \pm \frac{2}{3})$, $(\pm \frac{1}{3}, 0, \mp \frac{2}{3})$, $(\pm \frac{2}{3}, 0, \mp \frac{1}{3})$ rlu. Here we define the reciprocal lattice units (rlu), with in-plane components a_{pc} $= b_{pc} = 3.86$ Å (constrained by the NGO substrate) and the oo-p lattice constant $c_{pc} = 3.63$ Å for the Sm₉Ni₉O₂₂.

Complementary 4D-STEM measurements were carried out to further structurally characterize this phase $(Sm_9Ni_9O_{22})$ and determine the local structural modifications at the atomic level. Figure 2 shows the HAADF and 4D-STEM results obtained along different crystallographic orientations of the Sm₉Ni₉O₂₂. In Figure 2a,e are the Sm₉Ni₉O₂₂ HAADF images at higher magnification, corresponding to a projection of the NGO substrate along the $[001]_{o}$ zone axis. This is denoted as the 0° projection, or $[010]_{pc}$ zone axis, for the Sm₉Ni₉O₂₂ phase. The HAADF image shows the extended and reduced Sm-Sm distances, and one-third of the Sm column exhibits a doubling, with all of these reconstructions running periodically along the $\{303\}_{pc}$ stripes. 4D-STEM data collected simultaneously with the HAADF images are shown in Figure 2c,f. Figure 2b corresponds to the displacement intensity of the center-ofmass (COM) of the diffraction plane collected at every probe position, and donut shapes reveal the presence of atomic columns at their centers, even for oxygen atoms.^{30,31} Indeed, the lateral momentum transfer to the electron beam (Δp) is determined from these center-of-mass measurements. This Δp is negatively proportional to the in-plane electric field E_{i} thereby making Figure 2b a rough representation of in-plane electric field absolute intensity as well. The centers of the donut indicate then the presence of an atomic columns. Furthermore, the Figures 2c,f, can be considered as the divergence of in-plane electric field, thus approximating the projected charge-density image, with extrema located at the atomic positions. These images reveal unambiguously that columns of apical oxygen vacancies (Vo) are ordered along the stripes. This is causing the rare-earth superstructure, since the Sm atoms are moving away from the Vo sites giving separations between the Sm atoms of \approx 4.25 Å as shown in Figure 2e, while a reduced separation of ≈ 3.30 Å is measured when columns of apical oxygen are preserved. See Supporting Information, section 2 for these parameters in the structural models. Such local variations in the A-cation distances, arising due to the coexistence of different coordinations of B sites have been observed in studies of cobaltite,³² ferrite,³³ and manganite³⁴ systems.

A structural model showing a similar atomic reconstruction is shown in Figure 2d. This was obtained by an ab initio crystal relaxation of a cubic SmNiO₃, after introducing a single family of $(303)_{pc}$ planes of apical Vo. The presence of such planes of Vo leads to a mixture of octahedral and pyramidal Ni sites, and it forms the n = 3 member of a family made of $(n0n)_{pc}$ planes of Vo, with a formula $A_nB_nO_{3n-1}$. Interestingly, infinite-layer nickelates, with the formula RNiO₂ form the n = 1 member. The structural details of such $A_nB_nO_{3n-1}$ series as predicted by ab initio calculations are in Supporting Information, section 2.1.

The STEM images measured along a projection rotated by 90° compared to Figure 2a (corresponding to a substrate $[\overline{1}10]_{o}$ zone axis and a $[100]_{pc}$ Sm₉Ni₉O₂₂ zone axis) as shown in Figure 2g,h indicate that the vacancy ordering is taking place along two perpendicular projections. While the observation along the 0° projection of the Sm₉Ni₉O₂₂ was only showing $(303)_{pc}$ planes (e.g., and not a $(\overline{3}03)_{pc}$), panels k–m of Figure 2 show different domains in 90° projections, where the stripes coincide with the $(033)_{pc}$ or the $(0\overline{3}3)_{pc}$ planes. This indicates that 0 and 90° projections are not exactly symmetrical, which is most likely due to the orthorhombicity of the substrate, that causes an asymmetry between the two in-plane directions.

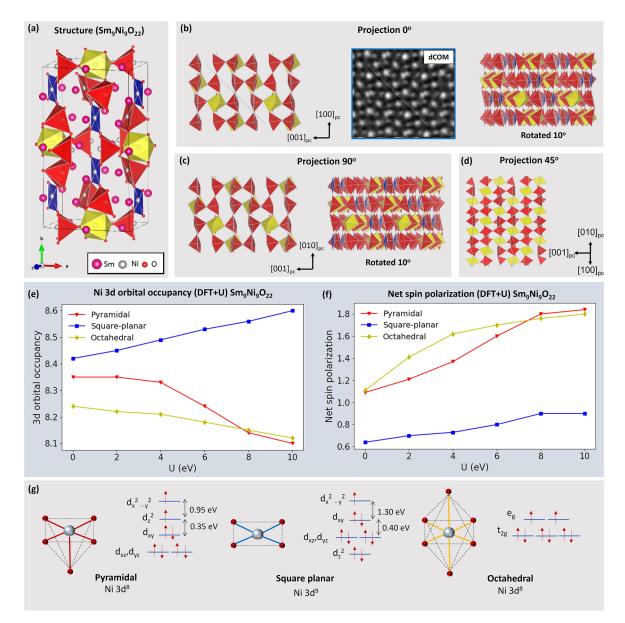


Figure 3. Structural and electronic refinements by DFT. (a) Relaxed structural model of $Sm_9Ni_9O_{22}$, with Ni sites in a mixed coordination of pyramidal, square planar, and octahedral. The axis indicated in this figure is the local axis with respect to the structure symmetry. (b) Polyhedral distribution viewed along $[010]_{pc}$ and a 10° rotation along [100], with the area matching with that of the dCOM image. (c) Polyhedral distribution viewed along $[100]_{pc}$ and a 10° rotation along [010]. (d) Polyhedral distribution viewed along [110]. From viewing along the three projections, the different polyhedra appear to have a periodic distribution. (e) Calculated 3d orbital occupancy of different Ni sites for U = 0-10 eV by DFT+U. (f) Calculated net spin polarization of different Ni sites are in a 3d⁸ configuration, while Ni in the square planar sites are in a 3d⁹ configuration. The indicated orbital energy differences are obtained from the calculated values from the RIXS fit, as indicated in Supporting Information, Table S3.

Nevertheless, locally both orientations reveal very similar cation and oxygen atomic reconstruction of the Sm₉Ni₉O₂₂. This essentially identifies that this phase is obtained by intersecting apical Vo planes of $(303)_{pc}$ and $(033)_{pc}$ orientations. Such a possible tetragonal symmetry is also confirmed by the observation along 45° projection as shown in Figure 2i,j. The apical oxygen removal indicatively reduces the o-o-p parameter, as is the case for infinite-layer nickelates, where the complete removal of apical oxygen results in an o-o-p parameter of ≈ 3.30 Å.^{8,35-37} The observed o-o-p parameter of 3.63 Å in Sm₉Ni₉O₂₂ is thus associated with these oxygen deficiencies.

Structural and Charge Ordering from Ab Initio Calculations. From these microscopic results, it is evident that this phase cannot be simply explained by one family of Vo planes, and intersecting $(303)_{pc}$ and $(033)_{pc}$ planes of apical vacancies are needed. Corresponding simulations involved the structural relaxations of a $6 \times 6 \times 6$ cubic SmNiO₃ supercell with $(303)_{pc}$ and $(033)_{pc}$ ordered apical Vo. The substrate constrained calculations resulted in a tetragonal structure with an o-o-p parameter of $c_{pc} = 3.63$ Å. This $6 \times 6 \times 6$ tetragonal supercell was then symmetrized, giving an 80-atom structure with the formula Sm₁₈Ni₁₈O₄₄, as shown in Figure 3a, which can be further shortened as Sm₉Ni₉O₂₂. More details are given

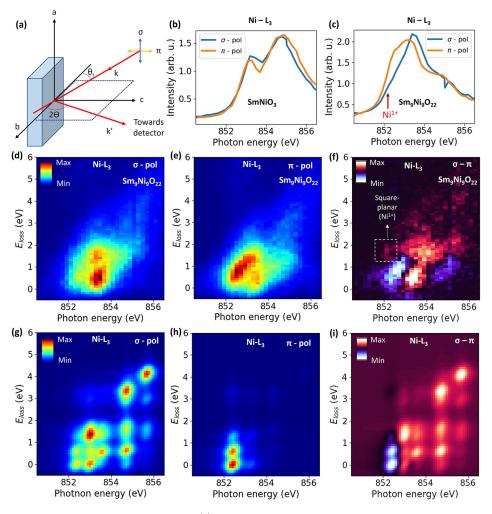


Figure 4. Electronic structure analysis by XAS and RIXS. (a) Experimental geometry showing the incident X-ray polarizations σ and π , incident X-ray angle θ_i , and the scattering angle 2 Θ . (b and c) XAS partial fluorescence yield (PFY) spectra at 25 K at Ni-L₃ edge of (b) SmNiO₃ and (c) Sm₉Ni₉O₂₂. (d and e) Ni-L₃ edge RIXS map at 25 K of Sm₉Ni₉O₂₂ in (d) σ —incident polarization—and (e) π —incident polarization of the photons. (f) Difference of RIXS map between the two polarizations. (g and h) Calculated Ni-L₃ edge RIXS map of Ni²⁺ pyramidal sites, in (g) σ -polarization and (h) π -polarization.(i) Difference of calculated RIXS map between the two polarizations.

in Experimental Section and Supporting Information, section 2. This structure essentially identifies three types of Ni sites: $\rm NiO_6$ octahedral (Oh), $\rm NiO_4$ square-planar (Sq), and $\rm NiO_5$ pyramidal (Py) in the ratio 1:2:6 in the lattice. In this regard, it is very different from the $A_3B_3O_7^{26}$ which have the Vo in the periodicity $\frac{1}{2}$ from the parent ABO₃ structure and is built with apical Vo lines running only along one projection. It is here also noted that an alternative A3B3O7 structure can also been obtained by mixing apical Vo $(303)_{pc}$ planes and equatorial Vo $(033)_{pc}$ planes, but the resulting structure would not match our observation (see Supporting Information, Figure S5).On the grounds of differently coordinated Ni sites in the lattice, a mixed valence is expected for the Sm₉Ni₉O₂₂ composition. Ab initio calculations give evidence of different Ni electronic configurations for the different site coordination as indicated by Figure 3e-g. Calculations have been done including a Hubbard U parameter ranging from 0 to 10 eV, as shown in Figure 3e,f. At U = 0 eV, differences of total charges on the Ni sites are already present but become more segregated between the square and the octahedra or the pyramid when U increases. The Ni in square planar sites are in a 3d⁹ configuration, indicating Ni^{1+} and a spin = 1/2 (typical occupation matrix is

given in Supporting Information, Table S2). The Ni in the pyramidal and octahedral sites are closer to a 3d⁸ configuration and a spin = 1. A $Sm_9Ni_9O_{22}$ composition would imply 17 charges to be distributed over the nickel sites and a possible distribution would then be 2 sq(Ni⁺, d^9), 6 Py(Ni²⁺, d^8) and a single Oh (Ni³⁺, $3d^{8}L$ with <u>L</u> referring to a hole in the ligand). The exact nature of the Ni³⁺ ground state (i.e., the respective weight of $3d^7$ and $3d^8 L$ in the ground state) is difficult to address solely based from the DFT+U level where, in brief, electron localization and correlation are brutally parametrized. We also assume that a ligand hole will reside on the octahedral sites by analogy from the electronic structure of the parent SmNiO₃ phase. In the metallic state, it is known to host octahedral Ni³⁺ with primary covalent ground state (a.k.a, as negative charge transfer), id est, primarily composed by a $3d^8L$. In the insulating state, the bond disproportionates with the presence of collapsed $d^{8}L^{2}$ and expanded d^{8} octahedral sites.³⁸ These charge distribution and orbital physics are summarized in Figure 3g, and they are further probed by spectroscopic techniques involving X-ray absorption spectroscopy (XAS), resonant inelastic X-ray scattering (RIXS) and hard X-ray photoemission spectroscopy (HAXPES).

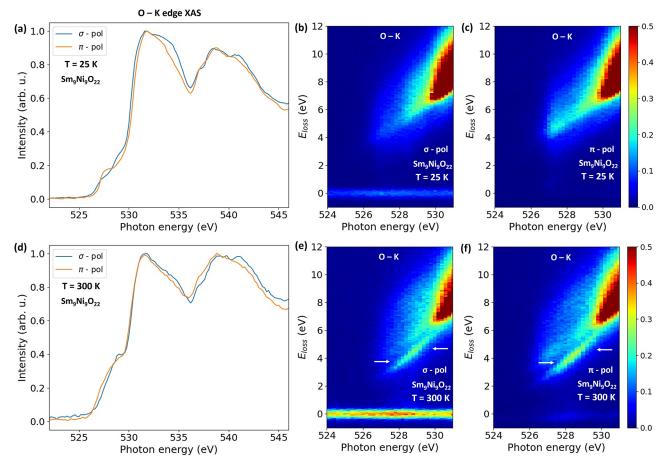


Figure 5. Temperature dependent spectroscopic studies at the O-K edge by XAS and RIXS maps (in energy loss) of Sm₉Ni₉O₂₂. (a-c) Measurements at T = 25 K, (a) O-K edge PFY XAS spectra in σ and π incident polarizations. (b and c) RIXS map at O-K edge for (b) σ incident photon polarization and (c) π incident photon polarization. (d-f) Measurements at T = 300 K, (d) O-K edge PFY XAS spectra in σ and π incident polarization and (c) π incident photon polarization. (d-f) Measurements at T = 300 K, (d) O-K edge PFY XAS spectra in σ and π incident polarizations, (e and f) RIXS map at O-K edge for (e) σ incident photon polarization and (f) π incident photon polarization. A low energy fluorescence line emerges at 300 K, as indicated by white arrows in the RIXS spectra.

Orbital Polarization and Charge Localization by Spectroscopic Measurements. The schematic of the XAS and RIXS measurements using a linearly polarized beam is briefly indicated in Figure 4a. The XAS Ni-L₃ edge of the parent perovskite SmNiO₃ thin film measured at 25K is given in Figure 4b which shows a typical splitting associated with bond disproportionation and the presence of collapsed $d^{8}L^{2}$ and expanded d^8 octahedra for the insulating state.³⁸ A more complete set of the XAS and RIXS data at the Ni-L edges measured for the parent SmNiO₃ thin film at RT (300 K) and 25 K can be seen in Supporting Information, Figure S7. They are in agreement with previously reported spectroscopic work on perovskite nickelate thin films,³⁹ and they show a fully developed insulating behavior at 25 K, and a partial metal-toinsulator transition occurring at RT (300 K) as revealed by a blurring of the XAS Ni-L₃ edges together with a blue shift of the localized dd-orbital excitations in the RIXS.³⁹ More discussion on this aspect is given in Supporting Information, Section 3. The Ni-L₃ edge XAS for the Sm₉Ni₉O₂₂ sample (Figure 4c) occurs at a lower excitation energy than that of $SmNiO_3$ indicating a reduced valence toward $\widetilde{Ni^{2+}}$ and Ni^{1+} as it was inferred from the structural investigation. In complement, a Ni $2p_{3/2}$ and Ni $2p_{1/2}$ core level bulk sensitive HAXPES measurements between Sm₉Ni₉O₂₂ and SmNiO₃ are given in Supporting Information, Figure S13 that shows a similar valence trend. Here, in Figure 4c, a strong dichroism is

observed at the Ni-L edges of the Sm₉Ni₉O₂₂ with a noticeable o-o-p higher intensity (corresponding to π -polarization) at the low-energy side of the Ni-L₃ main edge (at 852.5 eV). From atomic multiplet calculations (shown in Supporting Information, Section 4),⁴⁰ this strong dichroism is considered to be stemming from the Ni²⁺ in the pyramidal sites, which are the most populated in the lattice. By projecting the XAS final-state 2p⁵3d⁹ in terms of crystal field configuration, the features at 852.5 and 853.3 eV are identified respectively with $3d_{z^2-r^2}$ and $3d_{x^2-y^2}$ symmetry of the pyramidal sites explaining the sign and the hierarchy of the X-ray linear dichroism (XLD) signal.^{40,41} An in-plane contribution is also expected from the XAS spectra of the square planar $3d_{x^2-y^2}$ state of the Ni¹⁺, and it is at the origin of the shoulder observed at 852.3 eV for the σ polarization. Nevertheless, the overall shape of the XAS-XLD is dominated by the Ni²⁺ in the pyramidal site with only a smaller contribution of the Ni¹⁺ site in the square plane. These multivalent features of the Sm₉Ni₉O₂₂ structure are made clearer in the RIXS maps. The data for the σ - and π polarizations, along with their linear dichroisms, are displayed in Figure 4d-f. The RIXS data show dichroism similar to that observed in XAS, e.g., with a larger contribution in the π polarization at \approx 852.5 eV. The calculated RIXS maps obtained for a Ni²⁺ within a pyramid are in fair agreement with the experimental maps (Figure 4g-i). A noticeable difference on comparing Figure 4f,I is the experimental intensity at an energy

loss of 1.7 eV obtained for an excitation energy of ≈ 852.3 eV, which is not present in the calculation done for Ni²⁺. This excitation energy corresponds to Ni¹⁺, and its higher intensity for a σ -polarization is consistent with a square planar symmetry (see calculation in Figure S15), in accordance with $3d_{x^2-y^2} \rightarrow 3d_{xy}$, $3d_{xz}/3d_{yz}$ d-d transitions as also discussed by Rossi et al.⁴² in the case of an IL-nickelate. The RIXS signatures have also been investigated at RT for some excitation energies. The dichroic nature of Sm₉Ni₉O₂₂ is rather similar at room temperature, as shown in (Supporting Information, Figures S7 and S8), but some d-d transitions experience blue shift of ≈ 0.2 eV indicating electronic modification between low and room temperature.

In complement, similar spectroscopic studies have been carried out at the O-K edge for the parent and reduced phase, both at low and room temperature. O-K edge XAS has been previously used to investigate the electronic transition in a perovskite nickelate.⁴³ Here in the parent phase, along with the XAS, the electronic transition is further characterized by the RIXS maps that also indicates a band gap opening at low temperature (Supporting Information, Figures S9 and S10).

The O-K edge XAS and RIXS maps of Sm₉Ni₉O₂₂ shown in Figure 5a-f and in Supporting Information, Figures S11 and S12 are very different from the parent SmNiO₃. The prepeak of the O-K is very weak, which also confirms a reduced valency and covalency as compared to the Ni³⁺ of SmNiO₃. The position of the prepeak also confirms a band gap opening of \approx 3 eV for the reduced Sm₉Ni₉O₂₂. While being of small intensity, the prepeak shows a strong incident photon polarization dependence. At low temperature, this prepeak has stronger components at energies 527.2 eV for a σ polarization, then at 527.6 eV for a π -polarization and at 528.9 eV for a σ -polarization that could be interpreted by a combination of hybridization of the O-2p orbital with the unoccupied $3d_{x^2-y^2}$ of the Ni¹⁺ and then with the $3d_{z^2}$ and $3d_{x^2-y^2}$ of the Ni²⁺. This goes hand in hand with the respective energy positions of the calculated unoccupied density of states of these orbitals as shown in (Supporting Information, Figure S16).

The XAS O-K pre-edge at room temperature seems smeared out and exhibits a weaker dichroism. While observing the RIXS maps, a strong fluorescence line appears at room temperature causing the blurring of the O-K XAS pre-edge feature. This fluorescence line occurs for an incident photon energy corresponding to Ni-O hybridization and with the smallest energy loss, involving energy bands at the upper part of the valence band. A disappearance with temperature of this fluorescence line reveals an electronic phase transition and somehow a charge localization at low temperature for the Sm₉Ni₉O₂₂. Due to the weak dichroic character of this band, the localization might concern the Ni³⁺ in the octahedra whose electron configuration in the parent phase is also prone to charge localization.⁴⁴ Futhermore, additional electrons associated with oxygen deficient perovskite nickelates have also been predicted to strongly localize on octahedral sites, explaining the dramatic decrease in the electrical conductivity by several orders of magnitude in them.²⁷

CONCLUSIONS

Here, the topotactic reduction of a parent perovskite $SmNiO_3$ thin film grown on $NdGaO_3$ results in a homogeneous thin film of the $Sm_9Ni_9O_{22}$ phase, with in-plane parameters constrained on the substrate and a reduced pseudocubic o-o-

p parameter of 3.63 Å. This structure emerges from families of $\{303\}_{pc}$ apical oxygen vacancy (Vo) ordering giving a formula A₉B₉O₂₂ as revealed by 4D-STEM. A single family plane will give the A3B3O8 phase with only octahedral and pyramidal Ni sites. Here we show that the A₉B₉O₂₂ phase emerges from Vo families along two orientations, giving rise to square planar, pyramidal, and octahedral Ni sites. The square planar environment occurs at the intersection of orthogonal families and harbors a Ni¹⁺ indicating a possible route to IL-structure. It should be noted that such $(303)_{pc}$ phases have also been reported as structural defects, constrained in a quasi-2D nanosheet on the top of IL-NNO2.²⁴ In fact, such a $(303)_{pc}$ defect might be present as nanodomains, presumably along a single orientation, or overlap along different orientations and order at longer range as we showed here, enabling phase engineering in the ABO2-ABO3 system. In such case, this A9B9O22 phase could be a member of the family of nickel oxides that forms by $\{n0n\}_{pc}$ ordered Vo. Overlapping $(n0n)_{pc}$ and $(0nn)_{pc}$ apical oxygen vacancy planes result in a general formula $A_n^2 B_n^2 O_{3n^2-2n+1}$ that is indeed spanning from the IL-ABO2 with only square planar to the perovskite ABO3 with only octahedral Ni sites. In-between, octahedral, square planar and pyramidal sites are in the ratio $(n-2)^2:2:(4n-6)$. Such ${n0n}_{pc}$ planes could be seen as an analogous case of the Ruddlesden-Popper (RP) faults that is also present from the individual 2D defects and scale to a fully developed RP phase.

The stability of this family is still to be understood, and being an intermediate phase, it will depend on epitaxial strain and redox condition. This is in line with our observations indicating that the orthorhombic substrate plays a role, as strain in thin films is generally known to control the creation of Vo, even for the stabilization of superconducting IL-nickelate films.⁴⁵ Additionally, the choice of the reducing agent such as CaH_2 ,⁸ alumina¹¹ and atomic hydrogen²⁵ can influence the selective stabilization of each phase. The A₉B₉O₂₂ phase is also a neighbor of other members of the oxygen deficient nickelate series, such as the brownmillerite $ABO_{2.5}^{17}$ and the A₃B₃O₇.²⁶ The chemical dynamics behind the selective stabilization of these phases is still not understood. Possibly, this A₉B₉O₂₂ phase, that we report here, might have been present along the samples that reported the A₃B₃O₇,^{35,36} or it might have been misinterpreted as that.

Interestingly, ab initio calculations and spectroscopic studies coherently indicate that the Sm9Ni9O22 phase consists of tricomponent Ni sites, with a varying valence from Ni¹⁺ to Ni³⁺. Each component is associated with a unique symmetry, charge, orbital, and spin distribution, that collectively express a multivalent character with different degrees of orbital polarization at each site, as evidenced by our spectroscopic studies. The tricomponents are distributed in the lattice with a periodicity determined by the Vo ordering, contributing to a commensurate charge order for this system with a periodicity ($\frac{1}{2}$, 0, $\frac{1}{2}$) rlu. This periodicity is strikingly similar to that of the CO reported in IL-nickelate thin films.²⁰⁻²³ This possibly indicates the existence of this phase in IL-nickelate thin films as a defect, and this is further strengthened from recent studies reporting apical oxygen ordering in IL-nickelate thin films that exhibited similar CO.^{24,25} It questions how intrinsic is the $(\frac{1}{3},$ 0) rlu CO in IL-NdNiO₂.

The parent perovskite $SmNiO_3$ exhibits a metal-to-insulator (MIT) around 375 K as evidenced by our transport measurements, and this is similar to what was previously

reported²⁸ in these. However, the Sm₉Ni₉O₂₂ system has a complex multivalent electronic landscape, with an intriguing carrier localization contributing to an enhanced resistivity. This is in contrast with the case of oxide semiconductors, where Vo cause an enhanced conductivity. However, this is in line with previous reports on perovskite nickelates, where the Vo cause localization of electrons at the octahedral Ni sites,²⁷ with the subsequent filling of the ligand hole resulting in a $3d^8$ configuration. The oxygen deficient nickelate discussed in that report might correspond to this phase. Furthermore, RIXS evidence an additional charge localization at low temperature, presumably associated with the charge configuration at octahedral Ni site. It is worth noting that the Ni sites at the parent phase octahedra have known charge fluctuation $3d^{8}L$ \leftrightarrow $3d^8 + 3d^8 \underline{L}^2$ playing a role in the temperature driven MIT. This might be hindered for an isolated octahedron, giving rise to different charge fluctuation (e.g., $3d^{8}L \leftrightarrow 3d^{7}$), making the phase diagram of this system more complex.

On a broader perspective, this is another example of the idea of selective oxygen incorporation driving stabilization of phases/interfaces that have metallic, semiconducting, insulating, and even superconducting (with doping) properties.^{8,46–48} The carrier distribution in the lattice, which is associated with the distribution of oxygen atoms, has an identical effect as that of hydrogenated perovskite nickelate devices proposed for neuromorphic computing applications.¹⁵ This was demonstrated for an oxygen deficient NdNiO_{3- δ} nickelate device, that could potentially have this A₉B₉O₂₂ phase, where multiple resistance states were achieved by adjusting the electronic bias.²⁷ Such findings uncover the possible multitude of applications of this phase on par with other strongly correlated electron systems.

EXPERIMENTAL SECTION

Samples. Before growth, the $(110)_0$ -oriented NdGaO₃ singlecrystalline substrates were annealed at 1150 °C for 10 h in flowing oxygen to obtain sharp step-and-terrace surface morphology. Then the pristine 14 nm thick SmNiO₃ epitaxial thin films were grown by off-axis radio frequency magnetron sputtering, at a substrate temperature of 460 °C and a total pressure of 0.18 mbar with an oxygen/argon mixture of 1:3.⁴⁹ After growth, the samples were cut into pieces with the size of 5 × 2.5 mm² and loosely wrapped in the aluminum foil. The wrapped samples were then sealed under vacuum in Pyrex glass tubes, embedded with CaH₂ powder of ≈0.1 g. The sealed glass tubes were heated in a tube furnace to 230–240 °C for 1 h and cooled to room temperature at a rate of 10 °C/min.

High-Resolution HAADF-STEM Imaging and 4D-STEM. Cross-sectional transition electron microscopy (TEM) lamellae were prepared using a focused ion beam (FIB) technique (at C2N, University of Paris-Saclay, France). Before FIB lamellae preparation, around 20 nm of amorphous carbon was deposited on top for protection. The HAADF imaging and 4D-STEM were carried out in a NION UltraSTEM 200 C3/C5-corrected scanning transmission electron microscope (STEM). The experiments were done at 200 keV with a probe current of approximately 10 pA and convergence semiangles of 30 mrad. A MerlinEM instrument (Quantum Detectors Ltd.) in a 4×1 configuration (1024 \times 256) has been installed on a Gatan ENFINA spectrometer mounted on the microscope.⁵⁰ The EELS spectra are obtained using the full 4×1 configuration and the 4D-STEM by selecting only one of the chips (256×256 pixels). For 4D-STEM, the EELS spectrometer is set into non-energy dispersive trajectories and we have used 6-bit detector mode that gives a diffraction pattern with a good signal-to-noise ratio without compromising much on the scanning speed.

Ab Initio Calculations. The first-principles calculations were performed using the density functional theory⁵¹ as implemented in the Quantum ESPRESSO package.^{52,53} The exchange-correlation functional was approximated by the generalized gradient approach.⁵ Planewave cutoffs of 40 and 400 Ry were used for basis-set and charge density expansions, respectively. Structural relaxations were done without considering a Hubbard U parameter, while the electronic structure were calculated with it. All DFT+U calculations were performed with a J = 1.2 eV, making $U_{\text{effective}} = U - J$. All structural relaxations begin with creating a supercell from a cubic SmNiO₃, with a = 3.80 Å. Then, the oxygen atoms along the corresponding family of Vo planes were removed. For the Sm₉Ni₉O₂₂ phase, after removing the two orthogonal families of apical Vo, it results in a 960-atom 6×6 \times 6 supercell. The resulting pseudotetragonal o-o-p parameter of c =3.63 Å was obtained by minimizing the total force in a $6 \times 6 \times 6$ supercells (the in-plane pseudotetragonal parameter a = b = 3.90 Å, was frozen). This tetragonal supercell was then reduced using symmetry to an monoclinic 80-atom cell. Thus, the obtained structure has the space group C2/m and lattice parameters of a = 9.02, b =16.09, c = 6.47 Å, and $\beta = 87.57^{\circ}$. The structural parameters with atomic positions are given in Table S1. The lattice vectors of the tetragonal 960-atom phase $(\overrightarrow{a_T}, \overrightarrow{b_T}, \overrightarrow{c_T})$ expressed in the symmetrized monoclinic parameters $(\overrightarrow{a_m}, \overrightarrow{b_m}, \overrightarrow{c_m})$ a r e $\overrightarrow{a_{T}} = \overrightarrow{a_{m}} + \overrightarrow{b_{m}} + 2\overrightarrow{c_{m}}, \quad \overrightarrow{b_{T}} = \overrightarrow{a_{m}} - \overrightarrow{b_{m}} + 2\overrightarrow{c_{m}},$ a n d $\overrightarrow{c_T} = 2 \overrightarrow{a_m} - 2 \overrightarrow{c_m}.$

XAS and RIXS Measurements. The X-ray absorption spectroscopy (XAS) and resonant inelastic X-ray scattering (RIXS) measurements of the Ni-L edges and the O-K edge were performed at the AERHA instrument of the SEXTANTS beamline at the SOLEIL synchrotron. A detailed optical scheme of the spectrometer that involves dispersing the X-ray photons as a function of their energy onto a two-dimensional detector is given in ref 55 and the experimental geometry in Figure 4a. The measurements were performed with the *a* and *c* sample axes in the horizontal scattering plane. Measurements at the Ni-L and O-K edges were taken with θ_i = 20° (where θ_i is the angle between the incoming X-ray and the sample surface), and linear dichroism was obtained by switching the incident X-ray polarization between σ and π . RIXS was measured at $2\Theta = 85^{\circ}$, with an overall full width at half-maximum (fwhm) energy resolution of 170 \pm 10 meV for the O-K edge and 300 \pm 10 meV for the Ni-L edge. The measurements were done at T = 25 K and T = 300 K. The two-dimensional RIXS data are binned in the isoenergetic direction to form spectra, and the pixel to energy conversion is performed by measuring the position of the elastic line of the spectrometer while changing the beamline energy.

HAXPES Measurements. The measurements were carried out at the GALAXIES beamline at the SOLEIL synchrotron⁵⁶ on the HAXPES endstation⁵⁷ using a photon energy of 3000 eV, with an incidence angle of 10°. The bulk sensitivity is defined from the SESSA simulations,⁵⁸ which give a probing depth of around 10 nm for 10° incidence. About 95% of the detected signal will be from the elements within these estimated probing depths. The synchrotron operated with a ring current of 450 mA, giving an intensity of 3.4×10^{13} photons/s at 3000 eV, which was then reduced using a built-in filter to 5% of the original intensity. The photoelectrons were detected using a SCIENTA Omicron EW4000 HAXPES hemispherical analyzer, and a Shirley background⁵⁹ was removed prior to fitting the core levels spectra.

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ABBREVIATIONS

4D-STEM,	four-dimensional scanning transmission elec-				
	tron microscopy				
DFT	density functional theory				
GPA,	geometrical phase analysis				
HAADF-STEM,	high-angle annular dark-field-scanning				
	transmission electron microscopy				
HAXPES,	hard X-ray photoelectron spectroscopy				
RIXS,	resonant inelastic X-ray scattering				
XAS,	X-ray absorption spectroscopy				

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A valence-ordered thin-film nickelate with tri-component nickel coordination prepared by topochemical reduction

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1 HAADF-STEM imaging in low magnification

Here we present the HAADF-STEM images of the reduced $Sm_9Ni_9O_{22}$ thin-film (Figure S1) and parent SmNiO₃ (Figure S2) in a lower field of view. The observed uniform out-of-plane compression in Figure S1b can be ascribed to the proper stabilization of the thin-film of the reduced phase, devoid of any defects. All the measurements including 4D-STEM were carried out at room temperature at 200 keV with a probe current of approximately 10 pA, in these conditions, the samples did not show any beam damage. Optimized parameters were used for data acquisition that involved enhancing the signal to noise ratio, without compromising the scanning speed.

1.1 $Sm_9Ni_9O_{22}$

At larger field-of-view, the GPA map of the $Sm_9Ni_9O_{22}$ have homogeneous distribution indicating the absence of defect and the formation of a new phase.

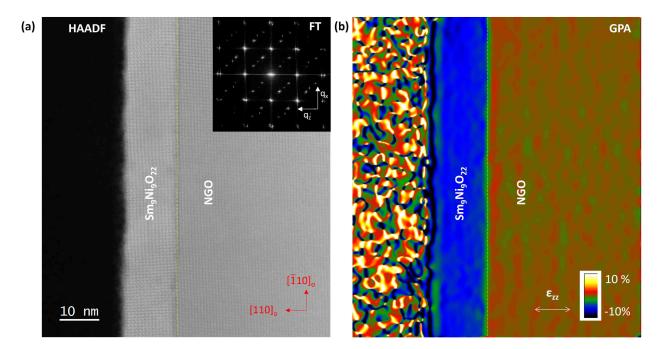


Figure S1: Structural homogeneity of $Sm_9Ni_9O_{22}$ thin-film. (a) Low magnification HAADF image of the $Sm_9Ni_9O_{22}$ thin-film, viewed along the $[010]_{pc}$ zone axis. A Fourier transform is shown in the inset. (b) The corresponding out-of-plane strain map by GPA. A uniform compression of 7% for the o-o-p parameter is observed for the whole $Sm_9Ni_9O_{22}$ thin-film (the substrate o-o-p is the reference), indicating the homogeneity of the thin-film.

1.2 SmNiO₃

The bulk SNO possesses an orthorhombic Pbnm structure and lattice parameters $a_o = 5.328$ Å, $b_o = 5.437$ Å and $c_o = 7.567$ Å. The SNO unit cell can be described by a pseudo-cubic unit with $a_{pc} = 3.799$ Å. The NGO substrate has $a_o = 5.433$ Å, $b_o = 5.503$ Å, and $c_o = 7.716$ Å when also expressed within Pbnm orthorhombic space group. The SNO thin film and substrate have structural continuity and thus similar crystallographic orientations when observed in STEM. Due to the substrate strain, the GPA derived pseudo-cubic out-of-plane value of SNO is 3.78Å.

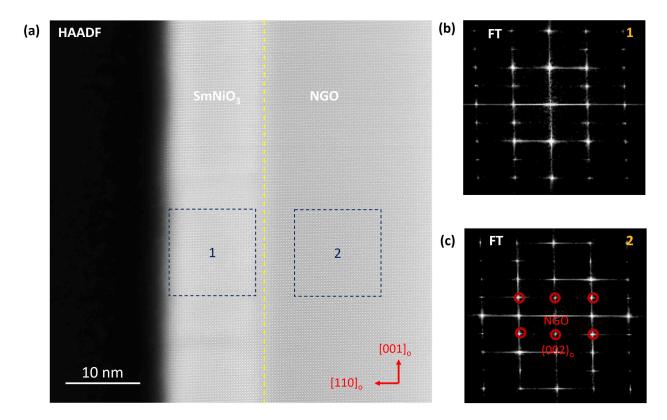


Figure S2: The Orthorhombic SmNiO₃ thin-film. (a) A low magnification HAADF image of SmNiO₃ thin film on the orthorhombic NdGaO₃ substrate with in-plane $[001]_o$ axis. (b & c) The Fourier Transform on (b) SmNiO₃ and (c) Substrate NdGaO₃.

2 Building the new phase with oxygen vacancies

2.1 Structural family of $A_n B_n O_{3n-1}$ formed by $(n0n)_{pc}$ oxygen vacancies plane

The Figures S3(a-f) show the positions of the columns of removed apical oxygens to form the $A_n B_n O_{3n-1}$ structure for n = 1 to n = 6 along with the corresponding stoichiometries. For the general case, the new structural family of $A_n B_n O_{3n-1}$ is thus formed by $(n0n)_{pc}$ oxygen vacancy planes starting on a cubic perovskite ABO₃. Such structures have then been relaxed by ab-initio either constraining or not the a,b axis to the substrate. The Figures S3g shows the resulting relaxed c-axis parameters in the case of Nd_nNi_nO_{3n-1} with and without the constrain by a SrTiO₃ substrate. This corresponds to the case of the most reported infinite-layer nickelate obtained by topotactic reduction, id est, the case of NdNiO₂ // SrTiO₃. The Figure S3h reports the resulting relaxed c-axis parameters in the case of Sm_nNi_nO_{3n-1}, free and constrained by substrate NdGaO₃, corresponding to the studied system in the main text. As expected, the c-axis parameters increase with the oxygen content (A_nB_nO_{3n-1}) from the IL-nickelate (n = 1) toward the parent perovskite that would be for n = ∞ . In the case of Nd_nNi_nO_{3n-1}, the c-axis parameter is around 3.65Å for n = 3, and it converges to about 3.75Å for n higher than 4 when it is not constrained. The constrain by the substrate result in overall shorter out-of-plane axis. Similar trends is obtained for the Sm_nNi_nO_{3n-1} with shorter c-axis parameters as expected due to the difference of Rare-Earth size.

Figure S4 shows the relaxed atomic structures of the $\text{Sm}_n \text{Ni}_n O_{3n-1}$ family for n = 1 to 4. The n = 1 case corresponds to that of an infinite-layer nickelate, with c = 3.22 Å. On observing the HAADF and 4D-STEM images along in-plane pseudo-cubic axis (the 0° or 90° projection mentioned in the main text), the experimental $\text{Sm}_9\text{Ni}_9O_{22}$ have a rather identical structure as the $A_3B_3O_8$ in Figure S4c (the n = 3 member). After relaxation, a short and a long distances inbetween Sm columns appear with respectively ≈ 3.60 Å and ≈ 4.30 Å. The presence of a Sm doublet (for 1/3 of the Sm columns) is noticeable and is also in agreement with the STEM observation. Similar kind of reconstructions are visible for the n = 4 member, but for instance, with more Sm doublets (*i.e.* for 1/2 of the Sm columns).

2.2 $A_9B_9O_{22}$ from intricating $\{303\}_{pc}$ Vo planes

In this section, we now focus on the cases where the oxygen deficient structures having a triple periodicity with respect to the cubic perovskite and discuss the corresponding Ni coordinations.

At first, we report in Figure S5a, the already proposed $A_3B_3O_7$ structure [1] which is resulting from removing oxygen from the apical sites on only one projection. The Ni sites is then existing in square-planar and octahedral coordinations with the oxygen atoms. Such a structure is very different from the STEM observation and spectroscopic observations.

In Figure S5b, the $A_3B_3O_8$ structure is resulting from removing oxygen from the apical sites with a (303)pc periodicity on one projection as discussed in the previous section. This results in Ni sites existing in pyramidal and octahedral coordinations with the oxygen atoms.

We then consider the case where several $\{303\}_{pc}$ oxygen vacancies planes are simultaneously removed since the experimental STEM data have demonstrated that $(303)_{pc}$ and $(033)_{pc}$ oxygen vacancy planes are coexisting in the experimental structure. Removing oxygen from the apical sites with a $(303)_{pc}$ and $(033)_{pc}$ periodicity (*i.e.* along two orthogonal projections) give the more oxygen reduced structure showed in Figure S5(c). It corresponds to A₃B₃O_{7.33} (A₉B₉O₂₂) stoichiometry. There, the Ni sites are existing in pyramidal, square-planar and octahedral coordinations with the oxygen atoms.

It can be compared with the the $A_3B_3O_8$ structure where removing oxygen from the apical (out-of-plane) sites with a $(303)_{pc}$ periodicity on one projection is now combined by removing the equatorial (in-plane) sites with $(033)_{pc}$ planes peridocity on the other orthogonal projection (Figure S5d). This results in Ni sites existing in pyramidal, and octahedral coordinations with the oxygen atoms.

It is interesting to note that theses structures encompass Ni being in octahedral, tetrahedral, pyramidal and squareplanar coordinations with the neighbouring oxygen atoms with complex distributions. Among them, only the $A_9B_9O_{22}$ phase has Ni sites in octahedral, pyramidal **and square-planar** coordinations as shown in Figure S5c, thereby suggesting the possible route toward the formation of IL-nickelate, where all Ni sites are in square-planar coordination with oxygen. The occurrence of square-planar coordination comes from the removal of apical oxygen planes over two different directions.

Having demonstrated these for a $3x_3x_3$ supercell of a cubic perovskite, a more general relaxation of the Sm₉Ni₉O₂₂ phase is carried out starting from a $6x_6x_6$ -supercell (such $6x_6x_6$ supercell before removing the oxygen atoms had 1080 atoms). This is shown in Figure S6. Beginning with a $6x_6x_6$ -cubic supercell of SmNiO₃, the $(303)_{pc}$ and $(033)_{pc}$ families of apical oxygen were removed (Figure S6a-b). The crystal was allowed to relax minimizing the total force under substrate constrain. The relaxation give a reduced c-axis parameter to 3.63 Å that is rather comparable to the c-axis of the A₃B₃O₈ structure where only one $(303)_{pc}$ families of apical oxygen was removed. This is also in fair agreement with the experimental values. The resulting 960-atom tetragonal structure is shown in different orientations (Figure S6d-f) and is comparable to the STEM experiments (e.g., the observation of long and short Sm-Sm distances o 4.10Å and 3.60Å along two perpendicular orientations). This structure was then reduced to a smaller primitive monoclinic unit cell using symmetry. The structural parameters of this monoclinic structure is given in Table S1. It is to note that, from the symmetrized monoclinic parameters (a_m , b_m , c_m) by : $a_T = a_m + b_m + 2c_m$, $b_T = a_m - b_m + 2c_m$, $c_T = 2a_m - 2c_m$.

This work clearly evidences that a new phase can be created by intricating $\{303\}_{pc}$ Vo planes. This A₉B₉O₂₂ phase could be a member of a potentially new family of nickel oxides, that forms by intricating $\{n0n\}_{pc}$ ordered Vo. Overlapping $(n0n)_{pc}$ and $(0nn)_{pc}$ apical oxygen vacancy planes results in a general formula $A_{n^2}B_{n^2}O_{3n^2-2n+1}$. It is indeed spanning from the IL-ABO₂ with only square planar to the perovskite ABO₃ with only octahedral Ni sites. In-between, octahedral, square-planar and pyramidal sites are in the ratio $(n - 2)^2 : 2 : (4n - 6)$. Such $\{n0n\}_{pc}$ planes could be seen as an analogous case of the Ruddlesden-Popper (RP) faults that is also present from the individual 2D defects and can scale to form fully developed RP phase.

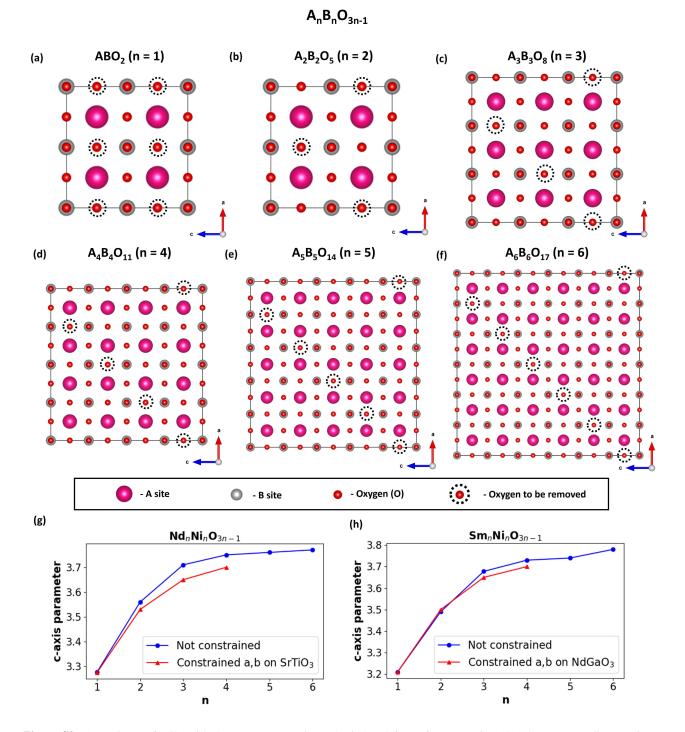
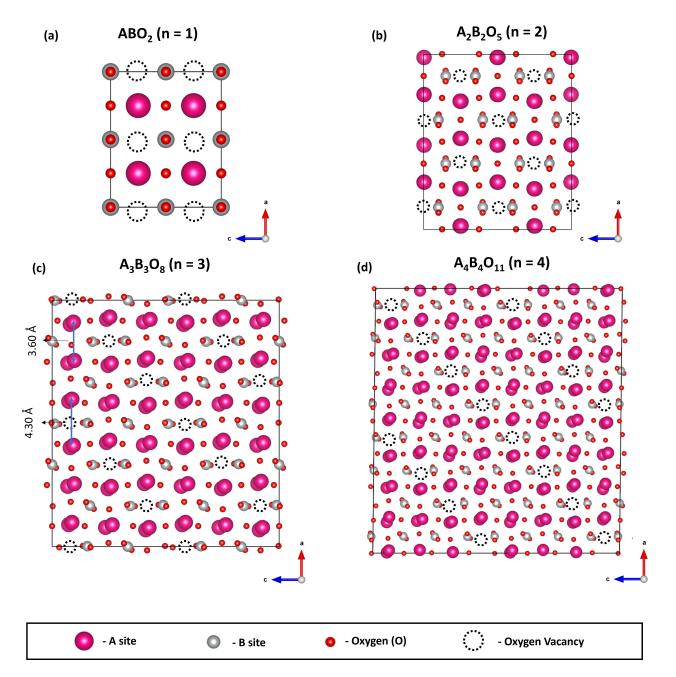


Figure S3: $A_n B_n O_{3n-1}$ family with the oxygen vacancies to be induced for (a-f) n = 1 - 6. (g,h) The corresponding c-axis parameters obtained by atomic relaxation for different n, with an without constraining in plane parameters on the substrate for a (g) $Nd_nNi_nO_{3n-1}//SrTiO_3$ system and (h) $Sm_nNi_nO_{3n-1}//NdGaO_3$ system. As it is evident, the c-axis parameters increases with the oxygen content ($A_nNi_nO_{3n-1}$). IL-nickelate corresponds to n = 1, while the parent perovskite would be for $n = \infty$. Furthermore constraining the in-plane parameters (NdGaO_3 : a = 3.86 Å, b = 3.86 Å and $SrTiO_3$: a = b = 3.91 Å) with these substrates reduces the c-axis parameter upon crystal relaxation, for n higher than 2.



 $A_n B_n O_{3n-1}$ (After relaxation)

Figure S4: Relaxed structures of the $Sm_nNi_nO_{3n-1}$ family with the oxygen vacancies (a-d) n = 1 - 4.

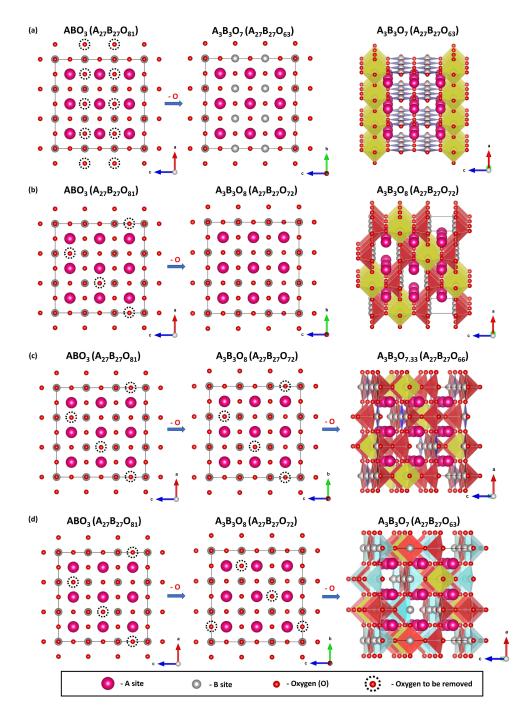


Figure S5: Different structures resulting by 1/3 removal of oxygen along various directions from a parent ABO₃ cubic 3x3x3 supercell. (a) The A₃B₃O₇ structure resulting from removing oxygen from the apical sites on one projection as shown. It results in Ni sites existing in square-planar and octahedral coordinations with the oxygen atoms. (b) The A₃B₃O₈ structure resulting from removing oxygen from the apical sites in Ni sites existing in pyramidal and octahedral coordinations with the oxygen atoms. (c) The A₃B₃O_{7.33} (A₉B₉O₂₂) structure resulting from removing oxygen from the apical sites with a (303)_{pc} periodicity. This results in Ni sites existing in pyramidal, square-planar and octahedral coordinations with the oxygen atoms. (d) The A₃B₃O₇ structure resulting from removing oxygen from the apical (out-of-plane) sites with a (303)_{pc} periodicity on one projection atoms oxygen from the apical (out-of-plane) sites with a (303)_{pc} periodicity on one projection atoms oxygen from the apical (out-of-plane) sites with a (303)_{pc} periodicity on one projection and equatorial (in-plane) sites with the same periodicity along the other orthogonal projection. This results in Ni sites existing in pyramidal, tetrahedral and octahedral coordinations with the oxygen atoms.

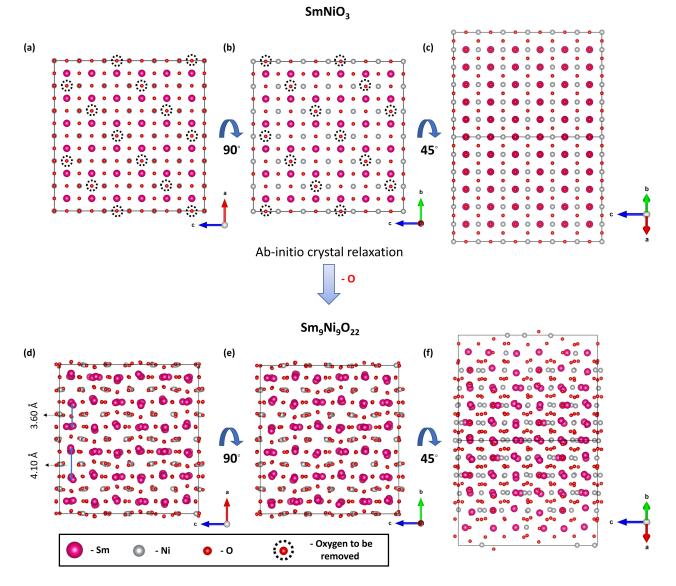


Figure S6: Ab-initio crystal structure relaxation of a 6x6x6 cubic supercell of SmNiO₃ with $(303)_{pc}$ and $(033)_{pc}$ oxygen vacancies, resulting in the SmNiO_{2.44} (Sm₉Ni₉O₂₂) structure. (a-c) The initial 6x6x6 supercell of cubic SmNiO₃ (a = 3.79 Å), along the (a) 0°, (b) 90°, and (c) 135° projections. Note that the oxygen vacancies to be induced are indicated in (a) and (b), but they are not indicated along the 135° projection in (c) due to overlap with other oxygen atoms. (d-f) The relaxed tetragonal structure along the (a) 0°, (b) 90°, and (c) 135° projections. The in-plane parameters (a = b = 3.79 Å) are kept the same, while the out-of-plane parameter is reduced (c = 3.63 Å).

S8

C2/m	a = 9.02Å	$b = 16.09 \text{\AA}$	$c = 6.47 \text{\AA}$	
(12)	$\alpha=90.00^\circ$	$\beta=87.57^\circ$	$\gamma=90.00^\circ$	
Atom	x	у	Ζ	
Ni1	0.13629	0.00000	-0.12659	
Ni2	-0.50000	0.00000	0.50000	
Ni3	0.31121	-0.16600	0.19587	
Ni4	0.00000	-0.16814	0.50000	
Sm1	0.00000	-0.18474	0.00000	
Sm2	-0.31539	-0.15216	0.29485	
Sm3	0.34038	-0.50000	0.64052	
Sm4	0.00000	-0.50000	1.00000	
01	0.09218	-0.08261	-0.33878	
02	-0.18560	-0.08740	-0.06043	
03	-0.63850	-0.08647	0.39467	
04	0.25000	-0.25000	0.00000	
05	-0.09169	-0.24204	0.31874	
06	-0.36078	0.00000	0.27300	
07	-0.50000	-0.14450	1.00000	

Table S1: The structural parameters of the $Sm_9Ni_9O_{22}$ monoclinic C2/m unit cell, reduced using symmetry from the relaxed 6x6x6 supercell. All the sites have an occupancy of 1.

3 Complementary Spectroscopic analysis of SmNiO₃ and Sm₉Ni₉O₂₂

Here we present temperature dependent XAS, RIXS measurements carried out on SmNiO₃ at the Ni-L and O-K edges. We also present RIXS measurements in $Sm_9Ni_9O_{22}$ in more details. This forms a comparative analysis between the well studied perovskite ABO₃ and the novel phase $A_9B_9O_{22}$.

3.1 The metal-to-insulator transition of SmNiO₃

As shown in Figure S7, the XAS and RIXS measurements with a linearly polarizerd light on SmNiO₃ at the Ni-L edge shows no strong dichroism, representative of symmetry of the octahedral NiO₆ coordination in this system. For instance, the XAS Ni-L3 spectra are similar for both polarisations in the total electron yield at 25K (Figure S7f), and they shows strong differences when compared to those at 300K (Figure S7g), indicating an electronic transition towards a more metallic state. Such a difference is similar to what discussed in Bisogni et al. [2] for NdNiO₃. In the RIXS signatures in Figure S7(b-e), the Ni dd-transition at around 1.3 eV shows a blue shift towards a higher energy loss with temperature, further indicating this metallic transition. Although the MIT of SmNiO₃ is at 375K, as evidenced by transport measurements, some regions of the thin-film near the surface can undergo a metallic transitions at a lower temperature. This is being reflected in our spectroscopic signatures at room temperature, and similar findings were also reported before [2].

The electronic transition evidenced from the Ni-L edge spectra is expected to give some spectroscopic signatures in the O-K edge. Here we discuss the O-K XAS and RIXS measurements on SmNiO₃ (Figures S9 and S10). A difference in the XAS spectra is observed for the O-K edge pre-peak, when going from 25K to 300K (Fig S9a and S9d). The pre-peak intensity at ca. 525.5 eV appear with lower intensity at room temperature. Furthermore, by overlapping the O-K pre-peak measured at both temperatures and normalizing their intensities as shown in Figure S10(j), the width of the pre-edge is also seen as narrower at lower temperature (25K) and a blue shift can also be observed (e.g., on the slope). This can be a possible representation of the spectroscopic nature of the MIT at the O-K edge. From a Ni-O hybridization model, the octahedral sites in the metallic regime of the perovskite nickelate [2, 3] are in a Ni $3d^8\underline{L}$ configuration with O-2p hole rich ground state. Such negative charge-transfer picture is at the origin of the strong pre-peak at the O-K edge. At lower temperature, the ground state has been described as altered, with two electron configurations, one for an expanded $3d^8$ Ni site and another one for a collapsed $3d^8\underline{L}^2$ Ni site. The reinforcement of the pre-edge intensity along with its narrowing might be relevant to this latest electron configuration. The small blue-shift of the O-K pre-edge can also be viewed in accordance with a band gap opening as expected from the MIT-like transition observed from the Ni-L edge at low temperature.

Corresponding RIXS O-K data have also been measured at both temperatures. They are represented in maps with the energy-loss as a function of the photon energy in Figure S9. They are also represented in a photon-in and photon-out maps in Figure S10. The narrower and stronger intensity of the pre-edges at low temperature, is now even more visible when looking at the energy-loss at ca. 525.5 eV in Figure S9. In Figure S10i, a very clear blue shift is measured at low temperature for the RIXS energy-loss profiles associated to the O-K pre-peak incoming photon energy, certainly in relation with a partial band-gap opening.

3.2 Temperature dependent electronic transitions in Sm₉Ni₉O₂₂

The XAS TEY spectra of $Sm_9Ni_9O_{22}$ at 300K is shown in Figure S7h, and it does not show a strong difference compared to the measurements at 25K as discussed in the main text. This can be attributed to a rather stability in the population for configurations associated with primary ionic electron configuration (Ni¹⁺ and Ni²⁺) as a function of temperature. Further investigation of this with respect to the Ni-L RIXS profiles is shown in Figure S8. Here, on comparing Figure S8 a and c, the dd-like transitions at around 0.8 eV, is having a small shift of around 0.2 eV to a higher energy loss at 25K. Considering the electronic picture from SmNiO₃, where RIXS signatures were obviously showing more sensitivity to small electronic change as compared to XAS, this can be an indication of some small evolution in the $Sm_9Ni_9O_{22}$ ground state at low temperature pertaining to the Ni-d orbital.

Interestingly, the O-K XAS edge was already showing variations between room and low-temperatures, as discussed in the main text. Specifically, the pre-peak in the O-K XAS shows a blurring at room temperature. Furthermore, there was a strong dichroic nature for these O-K prepeaks. As in the main text, Figure 5, the O-K XAS pre-edge in this system shows polarization dependent over the three peaks. They are stronger at energies 527.2 eV for a σ polarization, then at 527.6 eV for a π polarization and at 528.9 eV for a σ polarization. Some additional presentation of the RIXS spectra measured at the O-K is given in Figure S11 (maps) and S12 (profiles). Interestingly, on comparison with the RIXS map in Figure S11, we can interpret that these 3 peaks stay rather similar with temperature, although accompanied by a fluorescence line at a low energy loss that is appearing only at room temperature. This can also be seen in Figure S12, where the temperature dependant RIXS line profiles at resonance energies of 527.6 eV, 528.4 eV, and 528.9 eV are given. The peak representative of the fluorescence line emerges at 300K, and exists at the three incident energies. As discussed in the main text, the pre-peaks and their dichroic behavior can be compared with the density of states in Figure S16. They are the signature of the O-2p orbitals hybridized with the unoccupied $3d_{x^2-y^2}$ of the Ni¹⁺ and $3d_{z^2}$ of the Ni²⁺. Typically, the Ni²⁺ are the most populated sites giving birth to O-K pre-edge despite their rather ionic character.

The strong temperature difference is for a non-dichroic fluorescence line. It might concern the Ni³⁺ in octahedra. Indeed, by analogy of the peroskite nickelate, such valence is more prone to imply charge transfer configuration. Despite the small amount of such octahedral Ni³⁺ at room temperature, they thus might give a substantial spectral weight in the pre-edge. The subsequent disappearance of it at a low temperature points to the localization of these charge in the octahedral sites. Instead of the charge fluctuation of the perovskite parent phase, $3d^8\underline{L} \leftrightarrow 3d^8 + 3d^8\underline{L}^2$, the isolated Ni³⁺ of theSm₉Ni₉O₂₂ might have different one with temperature (e.g. $3d^8\underline{L} \leftrightarrow 3d^7$ more in accordance with the RIXS spectroscopic observation).

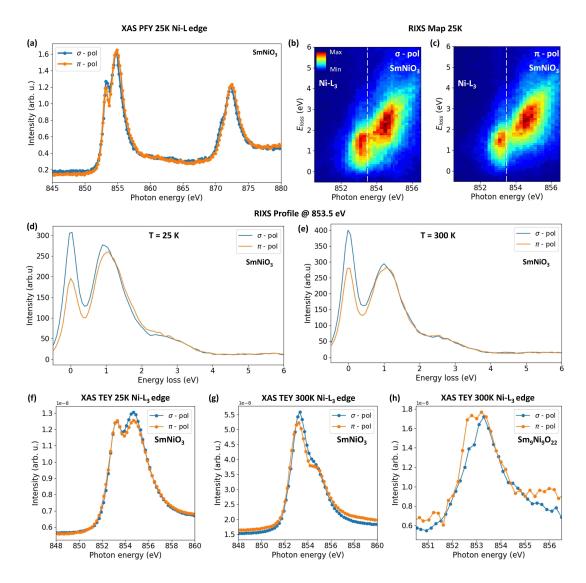


Figure S7: RIXS and XAS of SmNiO₃ and Sm₉Ni₉O₂₂. (a) Partial fluorescence yield (PFY) XAS spectra at Ni - L edge of SmNiO₃ in two incident photon polarizations at 25K. (b & c) The corresponding RIXS maps at Ni - L₃ of SmNiO₃ in (b) σ polarization and (c) π polarization. (d & e) Temperature dependent variations in RIXS XLD profile from both polarizations in SmNiO₃ at 853.5 eV for (d) T = 25 K and (e) T = 300 K. (f & g) Total electron yield (TEY) XAS spectra at Ni - L₃ edge of SmNiO₃ for two incident polarizations at (f) T = 25 K and (g) T = 300 K. (f) TEY XAS spectra at Ni - L₃ edge of Sm₉Ni₉O₂₂ for two incident polarizations at 300 K. The XAS spectra in PFY and TEY mode are identical, as depicted here for SmNiO₃. The TEY spectra of SmNiO₃ at 300K and 25K shows the metal-to-insulator transition, while the spectra of Sm₉Ni₉O₂₂ stays the same at 25K and 300K. Only TEY of the Ni-L are probed at 25K and 300K but they are very similar as the one reported by Bisogni et al. [2] showing that part of the thin film, certainly close to the surface is entering in the MIT coexistence. At RT, indeed the peak separation is getting smaller, and the width is changing very similarly as what they report by TEY in the case of NdNiO₃. RIXS probes more bulk and hence shows weaker differences. Nevertheless, a small shift to higher energy is seen at ≈ 1 eV energy loss measured at an excitation energy of 853.5 eV. It shows, at least, a partial charge disproportion when compared to the RIXS reported by Bisogni et al. [2].

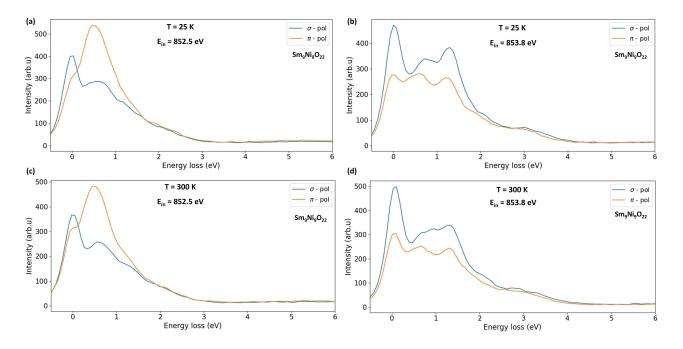


Figure S8: Temperature dependant RIXS line Profile of $Sm_9Ni_9O_{22}$ at different photon energies. (a & b) The measurements at 25K, for a photon energy of (a) 852.5 eV and (b) 853.8 eV. (c & d) The measurements at 300K, for a photon energy of (c) 852.5 eV and (d) 853.8 eV.

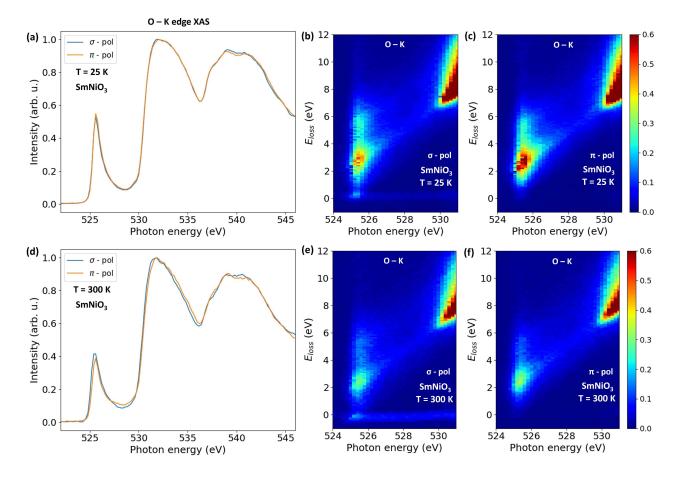


Figure S9: Temperature dependent spectroscopic studies at the O-K edge by XAS and RIXS (in energy loss scale) of SmNiO₃. (a-c) Measurements at T = 25 K, (a) O-K edge PFY XAS spectra in σ and π incident polarizations, (b & c) RIXS map at O-K edge for (b) σ incident photon polarization and (c) π incident photon polarization. (d-f) Measurements at T = 300 K, (d) O-K edge PFY XAS spectra in σ and π incident polarizations, (e & f) RIXS map at O-K edge for (e) σ incident photon polarization and (f) π incident photon polarization. Notably, as seen in XAS and made even clearer in the RIXS maps, the energy width of the O-K pre-edge is getting narrower and is shifted to a higher absorption energy at low temperature. Similar narrowing at the XAS pre-edges was reported for a nickelate metal-to-insulator transition (MIT) [3], confirming that some domains have a metallic character at RT. As expected, the parent structure has a weak dichroism for its spectral signatures, including the Raman-like energy loss features (less than 0.5 eV) only at RT, in a rather similar way that was reported with low-energy electron-hole pair continuum at the Ni-L edge RIXS for a metallic nickelate [2].

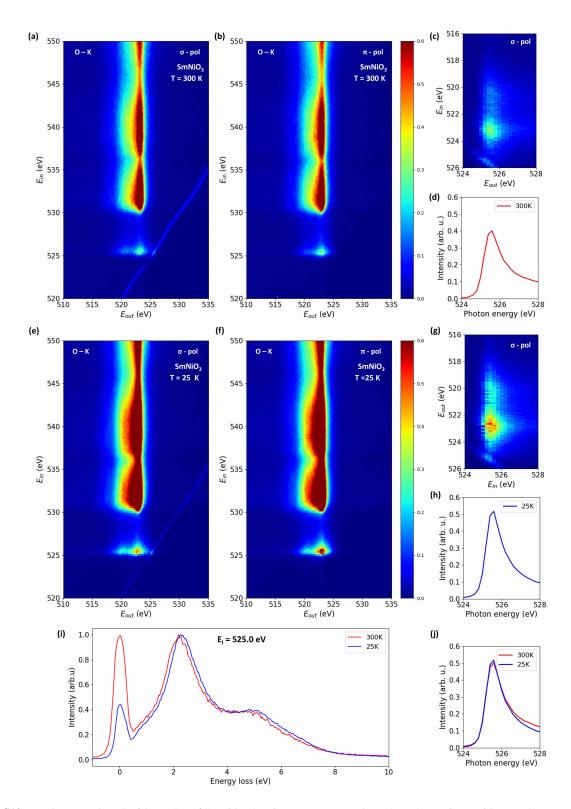


Figure S10: RIXS Map and XAS of O-K edge of SmNiO₃ showing a temperature dependent electronic transition. (a-d) Measurements at 300K. (a,b) RIXS map in incident (E_{in}) and detected (E_{out}) photon energy scales for (a) σ and (b) π incident photon polarisations, (c) A magnified RIXS map of a selected region in (a), (d) The XAS PFY plot of the O-K pre-edge, combining both polarisations. (e-h) Measurements at 25K. (e,f) RIXS map in incident (E_{in}) and detected (E_{out}) photon energy scales for (e) σ and (f) π incident photon polarisations, (g) A magnified RIXS map of a selected region in (e), (h) The XAS PFY plot of the O-K pre-edge, combining both polarisations, (i) Comparing the RIXS line profile at an incident photon energy of 525.0 eV for temperatures 300K and 25K, showing a blue shift at 25K. (j) The normalized-maxima-aligned pre-edge of O-K, for both temperatures. It shows a wider pre-edge at 300K.

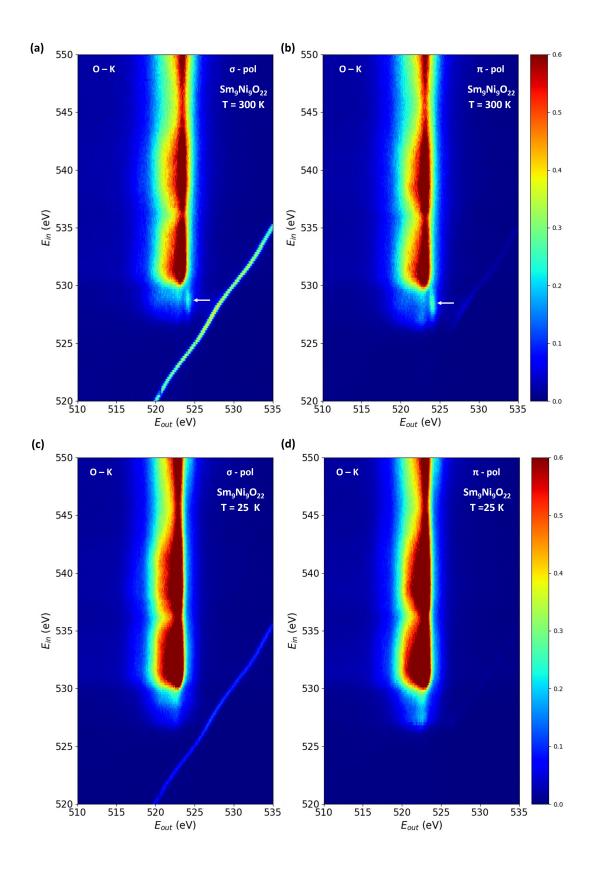


Figure S11: RIXS Map of O-K edge of Sm₉Ni₉O₂₂ showing the electronic transition at different temperatures.(a,b) RIXS map in incident (E_{in}) and detected (E_{out}) photon energy scales for (a) σ and (b) π incident photon polarisations at 300K, the low-energy loss fluorescence line is indicated by the white arrow. (c,d) RIXS map in incident (E_{in}) and detected (E_{out}) photon energy scales for (c) σ and (d) π incident photon polarisations at 25K.

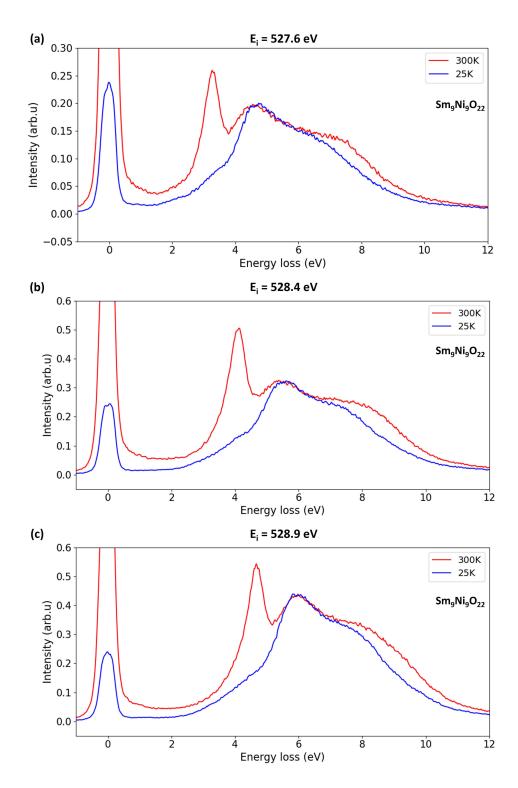


Figure S12: Temperature dependant RIXS line Profile of $Sm_9Ni_9O_{22}$ at different photon energies for the σ polarised incident photons. The spectra at an incident photon energy of (a) 527.6 eV, (b) 528.4 eV, and (c) 528.9 eV.

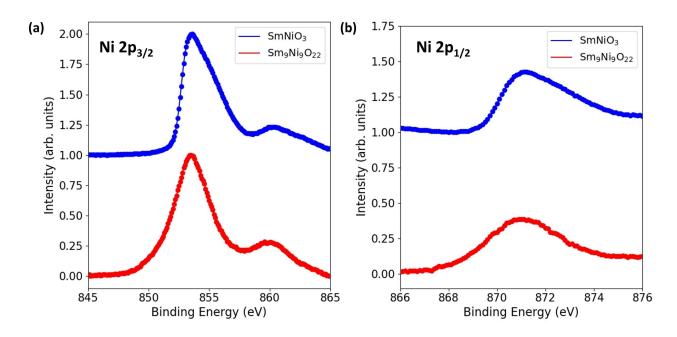


Figure S13: HAXPES comparison of $Sm_9Ni_9O_{22}$ and $SmNiO_3$ for (a) Ni $2p_{3/2}$ and (b) Ni $2p_{1/2}$ core levels. The measurements were done in a bulk sensitive mode, probing the whole thin-film. In both, $Sm_9Ni_9O_{22}$ has a low binding energy (LBE) shoulder, indicative of the Ni¹⁺ in the square-planar sites. The bulk-probing capacity of HAXPES makes it insensitive to possible surface contaminations or artefacts. One noticeable difference is the presence of a low binding energy (LBE) shoulder for $Sm_9Ni_9O_{22}$ compared to $SmNiO_3$ that can also be attributed to the Ni²⁺ and Ni¹⁺ sites.

4 Electronic structure simulations

The orbital occupancy, net spin polarization, and density of states of $Sm_9Ni_9O_{22}$ were calculated using DFT+U framework of Quantum ESPRESSO code [4, 5]. The DFT+U calculations were performed with a J = 1.2 eV, making $U_{effective}$ = U - J, on the symmetrized monoclinic $Sm_9Ni_9O_{22}$ unit cell given in Table S1. The Ni 3d orbital occupancy obtained for a U of 6 eV and a J of 1.2 eV is given in Table S2. It evidences the square-planar Ni site to be in a $3d^9$, pyramidal and octahedral Ni sites to be in a $3d^8$ occupancies. The corresponding spin-polarized density of states is shown in Figure S16.

The multiplet calculations were performed using CTM4XAS, CTM4RIXS [6], and Quanty [7]. The calculation for a D_{4h} Ni²⁺ was done in CTM4XAS and CTM4RIXS using the crystal field parameters $D_q = 0.13$ eV, $\Delta_t = 0.07$ eV, $\Delta_s = 0.15$ eV. The dichroic XAS results for the Ni-L edge are shown in Figure S14, and the RIXS results are shown in Figure 4 in the main text. Additionally, the RIXS map for a D_{4h} Ni¹⁺ was done using Quanty, with $D_q = 0.13$ eV, $\Delta_t = 0.10$ eV, $\Delta_s = 0.30$ eV for the crystal-field parameters. The results are shown in Figure S15. From these, the obtained orbital energy level values are shown in Table S3.

Ni site	Spin	$\mathbf{d}_{x^2-y^2}$	\mathbf{d}_{z^2}	\mathbf{d}_{xy}	\mathbf{d}_{xz}	\mathbf{d}_{yz}
Square-	up	0.81	0.98	0.91	0.98	0.98
planar	down	0.16	0.97	0.77	0.97	0.98
Pyramidal	up	0.96	0.97	0.99	0.99	0.99
r yrannuar	down	0.17	0.20	0.98	0.98	0.99
Octahedral	up	0.98	0.98	0.99	0.99	0.99
Octaneurai	down	0.13	0.16	0.98	0.98	0.98

Table S2: Occupation of 3d orbital in different Ni sites in $Sm_9Ni_9O_{22}$ by DFT calculations with a Hubbard U parameter of 6 eV and Hund's J parameter of 1.2 eV. The absolute values of the results indicates a $3d^8$ occupancy for the pyramidal and octahedral Ni sites, with a $3d^9$ occupancy for the square-planar sites.

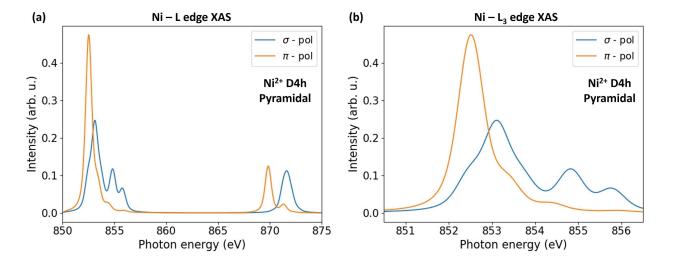


Figure S14: CTM4XAS [6] calculation of Ni²⁺ in D4h for the pyramidal sites. (a) Results for both polarizations for the Ni-L edge, (b) a magnified Ni-L₃ edge for both polarizations. It has been obtained using $D_q = 0.13 \text{ eV}$, $\Delta_t = 0.07 \text{ eV}$, $\Delta_s = 0.15 \text{ eV}$ for the crystal-field parameters. Same parameters are used for the RIXS calculations. It gives the following orbital energetic hierarchy : $E_{x^2-y^2}(b_{1g}) = 0 \text{ eV}$ (reference) ; $E_{z^2-r^2}(a_{1g}) = -0.95 \text{ eV}$; $E_{xz/yz}(e_g) = -1.30 \text{ eV}$; $E_{xy}(b_{2g}) = -1.40 \text{ eV}$

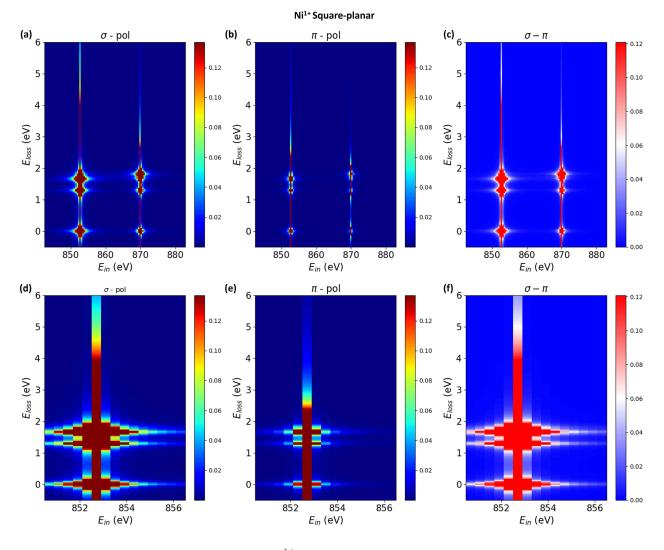


Figure S15: Calculated RIXS map at Ni-L edge of Ni¹⁺ Square-planar sites by Quanty [7]. (a) Results for σ polarization, (b) π polarization, (c) Difference of both polarization ($\sigma - \pi$). (d-f) The magnified map at the Ni-L₃ edge. It has been obtained using $D_q = 0.13 \text{ eV}$, $\Delta_t = 0.10 \text{ eV}$, $\Delta_s = 0.30 \text{ eV}$ for the crystal-field parameters. It gives the following orbital energetic hierarchy : $E_{x^2-y^2}(b_{1g}) = 0 \text{ eV}$ (reference); $E_{xy}(b_{2g}) = -1.30 \text{ eV}$; $E_{z^2-r^2}(a_{1g}) = -1.70 \text{ eV}$; $E_{xz/yz}(eg) = -1.70 \text{ eV}$.

Ni site	D_q	Δ_t	Δ_s	$E_{x^2-y^2}$	E_{xy}	$E_{z^2-r^2}$	$E_{xz/yz}$
Pyramidal	0.13 ev	0.07 ev	0.15 eV	0 eV	-0.95 eV	-1.30 eV	-1.40 eV
Square-planar	0.13 eV	0.10 eV	0.30 eV	0 eV	-1.30 eV	-1.70 eV	-1.70 eV

Table S3: Table showing the obtained energy level values for $Ni^{2+} D_{4h}$ pyramidal and $Ni^{1+} D_{4h}$ Square-planar sites from fitting the RIXS data using CTM4XAS and Quanty.

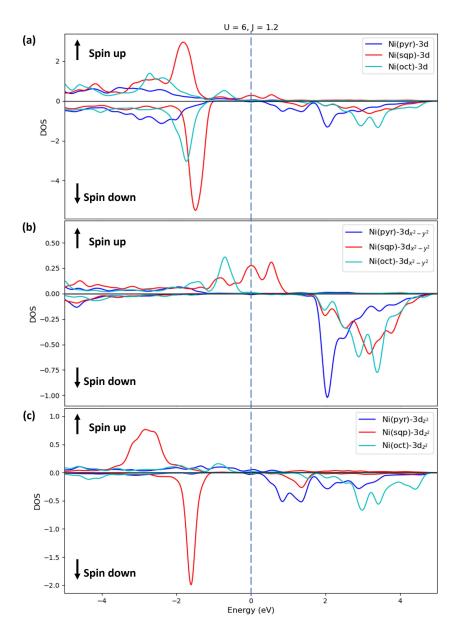


Figure S16: Partial density of states of different Ni sites in Sm₉Ni₉O₂₂ from DFT+U calculations, for U = 6 and J = 1.2 eV for (a) Total 3d orbital, (b) $3d_{x^2-y^2}$ orbital, and (c) $3d_{z^2}$ orbital. A first approximation is to consider the O-K edge as a probe of the unoccupied densities of state with O-2p character. The O-K pre-peak is then arising from the hybridization of the O-2p with the Ni-d band. When comparing the partial density of states above the Fermi level, alternating sequence of in-plane $(3d_{x^2-y^2})$, out-of-plane $(3d_{z^2})$ and in-plane $(3d_{x^2-y^2})$ states are legible, in agreement with the σ and π dependence of the XAS measurement.

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